TOSHIBA Transistor Silicon NPN Triple Diffused Mesa Type

2SD2638

Horizontal Deflection Output for Color TV, Digital TV **High Speed Switching Applications**

High voltage: $V_{CBO} = 1700 \text{ V}$

Low saturation voltage: $V_{CE (sat)} = 5 V (max)$

High speed: $t_f = 0.8 \mu s \text{ (max)}$

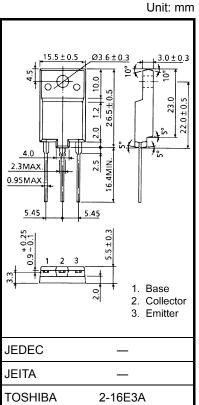
Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V_{CBO}	1700	V	
Collector-emitter voltage		V _{CEO}	750	V	
Emitter-base voltage		V_{EBO}	5	V	
Collector current	DC	Ic	7	Α	
	Pulse	I _{CP}	14		
Base current		ΙΒ	3.5	Α	
Collector power dissipation		PC	50	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the

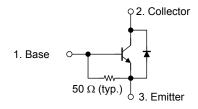
reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

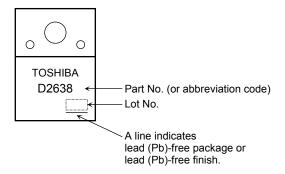


Weight: 5.5 g (typ.)

Equivalent Circuit



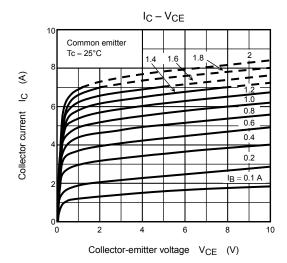
Marking

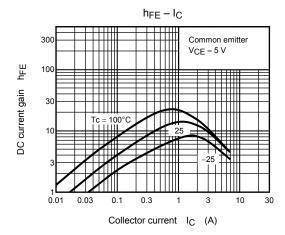


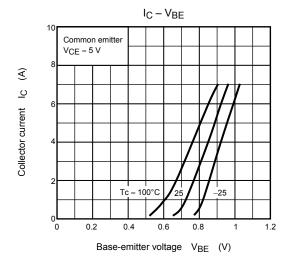
Electrical Characteristics (Tc = 25°C)

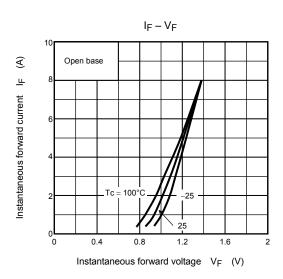
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	V _{CB} = 1700 V, I _E = 0	_	_	1	mA
Emitter cut-off current		I _{EBO}	V _{EB} = 5 V, I _C = 0	66	_	200	mA
Emitter-base breakdown voltage		V (BR) EBO	I _E = 400 mA, I _C = 0	5	_	_	V
DC current gain		h _{FE} (1)	V _{CE} = 5 V, I _C = 1 A	8	_	25	
		h _{FE} (2)	V _{CE} = 5 V, I _C = 5.5 A	4.5	_	7.5	
Collector-emitter saturation voltage		V _{CE} (sat)	I _C = 5.5 A, I _B = 1.2 A	_	_	5	V
Base-emitter saturation voltage		V _{BE} (sat)	I _C = 5.5 A, I _B = 1.2 A	_	1.0	1.5	٧
Forward voltage (damper diode)		V _F	I _F = 7 A	_	1.3	2	V
Transition frequency		f _T	V _{CE} = 10 V, I _C = 0.1 A	_	2	_	MHz
Collector output capacitance		C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	125	_	pF
Switching time	Storage time	t _{stg}	I _{CP} = 5.5 A, I _{B1 (end)} = 1.1 A, f _H = 15.75 kHz	_	7	9	μS
	Fall time	t _f		_	0.4	0.8	

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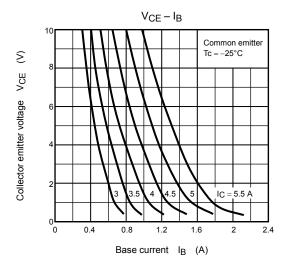


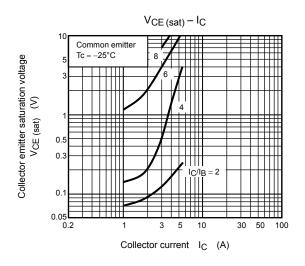


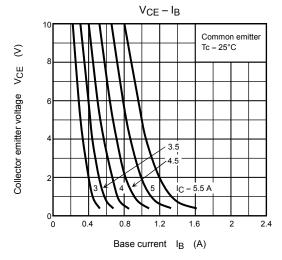


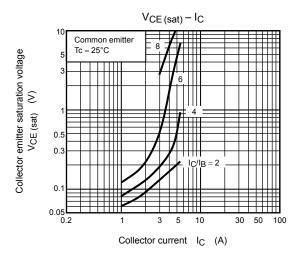


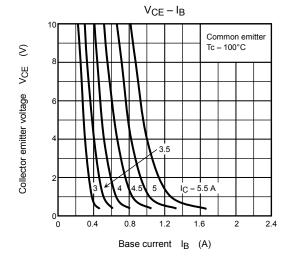
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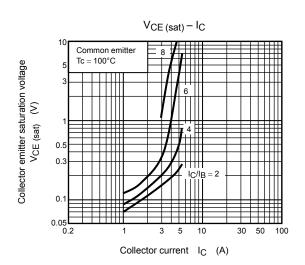


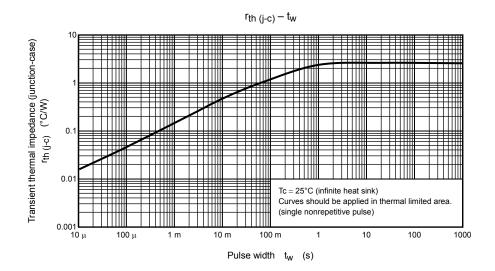


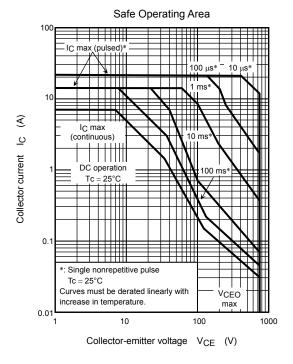


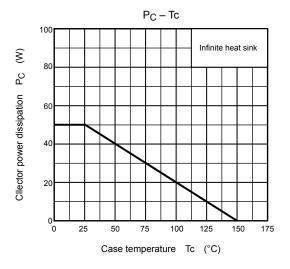












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